1N4148W-V



Vishay Semiconductors

Small Signal Fast Switching Diode

FEATURES

• These diodes are also available in other case styles including the DO-35 case with the type designation 1N4148, the MiniMELF case with the type designation LL4148, and the SOT-23 case with the type designation IMBD4148-V.



RoHS

COMPLIANT

- Silicon epitaxial planar diode
- Fast switching diodes
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

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MECHANICAL DATA

Case: SOD-123

Weight: approx. 10.3 mg

Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE					
PART	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS	
1N4148W-V	1N4148W-V-GS18 or 1N4148W-V-GS08	A2	Single diode	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	75	V	
Repetitive peak reverse voltage		V _{RRM}	100	V	
Average rectified current half wave rectification with resistive load ⁽¹⁾	f ≥ 50 Hz	I _{F(AV)}	150	mA	
Surge forward current	t < 1 s and T_j = 25 °C	I _{FSM}	500	mA	
Power dissipation ⁽¹⁾		P _{tot}	350	mW	

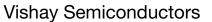
THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air ⁽¹⁾		R _{thJA}	375	K/W	
Junction temperature		Тj	150	°C	
Storage temperature		T _{stg}	- 65 to + 150	°C	

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature.

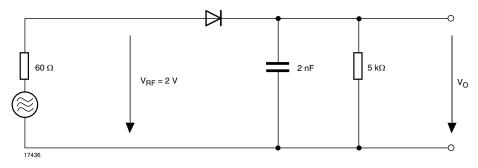
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1N4148W-V

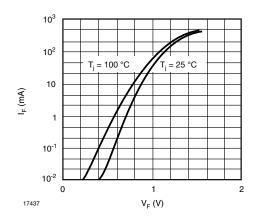


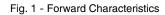
ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 10 mA	V _F			1000	mV
	I _F = 100 mA	VF			1200	mV
Leakage current	V _R = 20 V	I _R			25	nA
	V _R = 75 V	I _R			5	μA
	V _R = 100 V	I _R			100	μA
	V _R = 20 V, T _J = 150 °C	$\begin{array}{c ccccc} 00 \text{ V} & I_{\text{R}} & 100 \\ \hline = 150 ^{\circ}\text{C} & I_{\text{R}} & 50 \end{array}$	50	μA		
Diode capacitance	$V_{\rm F} = V_{\rm R} = 0 \ {\rm V}$	C _D			4	pF
Voltage rise when switching ON	Tested with 50 mA pulses, $t_p = 0.1 \ \mu s$, rise time < 30 ns, $f_p = (5 \text{ to } 100) \text{ kHz}$	V _{fr}			2.5	V
Reverse recovery time	$I_F = 10 \text{ mA}, i_R = 1 \text{ mA}, V_R = 6 \text{ V}, \\ R_L = 100 \ \Omega$	t _{rr}			4	ns
Rectification efficiency	f = 100 MHz, V _{RF} = 2 V	ην	0.45			

RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT



TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)





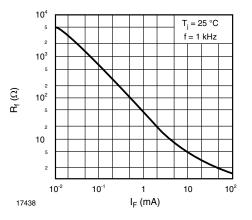


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

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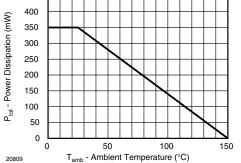


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

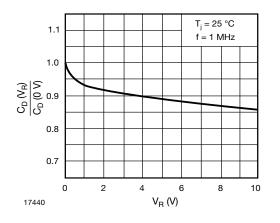


Fig. 4 - Relative Capacitance vs. Reverse Voltage

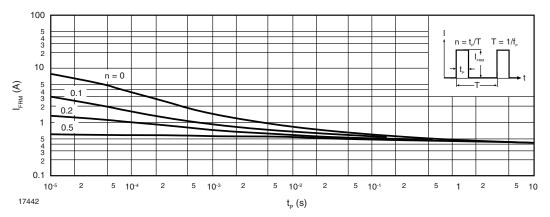


Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration

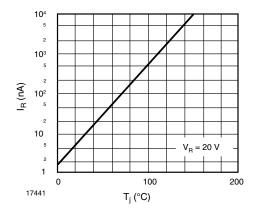


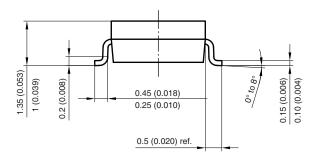
Fig. 5 - Leakage Current vs. Junction Temperature

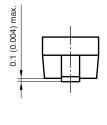
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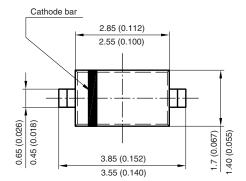


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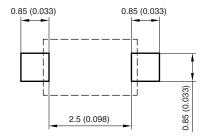
PACKAGE DIMENSIONS in millimeters (inches): SOD-123







Mounting Pad Layout



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